

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	115026	BP or (boron near phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:29
L2	205	group-III near3 nitride near3 semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:30
L3	3705	nitride near2 compound near2 semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:30
L4	27	I1 and I2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:30
L5	22	I1 and I3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:31
L6	26566	GaN or (gallium near nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:31
L7	970	I1 and I6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:31
L8	145	I7 and amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/27 16:34